AN6554, AN6554NS

Quadruple Operational Amplifiers

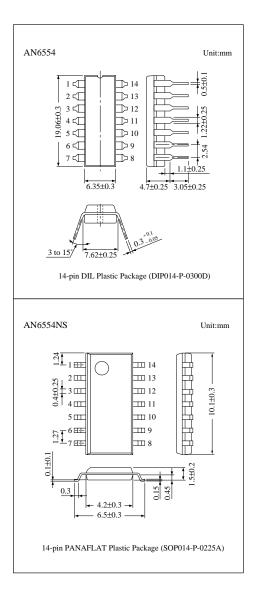
Overview

The AN6554 and the AN6554NS are quadruple operational amplifiers with phase compensation circuits built-in.

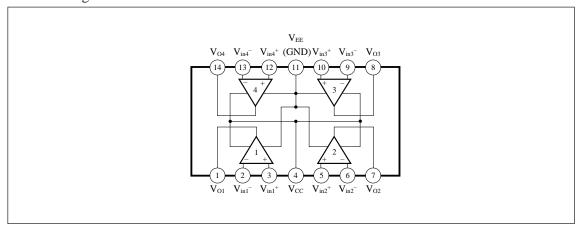
They are suitable for application to various electronic circuits such as active filters and audio pre-amplifiers.

■ Features

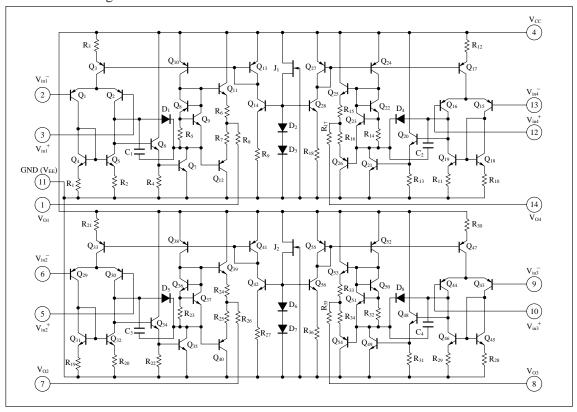
- Phase compensation circuit built-in
- High voltage gain, low noise
- Output short-circuit protection built-in



■ Block Diagram



■ Schematic Diagram



■ Pin Descriptions

Pin No.	Pin name	Pin No.	Pin name	
1	Ch.1 output	8	Ch.3 output	
2	Ch.1 inverting input	9	Ch.3 inverting input	
3	Ch.1 non inverting input	10	Ch.3 non inverting input	
4	V_{CC}	11	V _{EE} (GND)	
5	Ch.2 non inverting input	12	Ch.4 non inverting input	
6	Ch.2 inverting input	13	Ch.4 inverting input	
7	Ch.2 output	14	Ch.4 output	

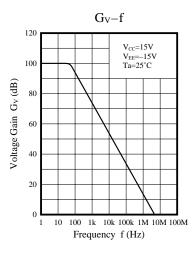
■ Absolute Maximum Ratings (Ta=25°C)

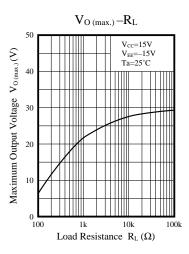
Parameter		Symbol	Rating	Unit		
Voltage	Supply voltage		V _{CC}	36	V	
	Differential input voltage		$V_{ m ID}$	±30	V	
	Common-mode input voltage		V _{ICM}	±15	V	
Power dissipation AN6554 AN6554NS		AN6554	- P _D -	570	337	
		AN6554NS		380	mW	
	Operating ambient temperature		$T_{ m opr}$	-20 to +75	°C	
Temperature	Storage temperature -	AN6554	T_{stg}	-55 to +150	°C	
		AN6554NS		-55 to +125		

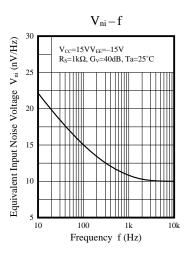
■ Electrical Characteristics (V_{CC}=15V, V_{EE}=-15V, Ta=25°C)

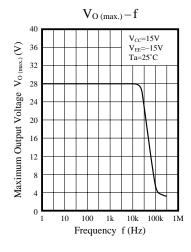
Parameter	Symbol	Condition	min	typ	max	Unit
Input offset voltage	V _{I (offset)}	$R_S \leq 10k\Omega$	_	0.5	5	mV
Input offset current	I _{IO}			5	50	nA
Input bias current	I _{bias}			100	300	nA
Voltage gain	G_{V}	$R_L \ge 2k\Omega$, $V_O = \pm 10V$	88	100	_	dB
Maximum output voltage	V _{O (max.1)}	$R_L \ge 10 k\Omega$	±12	±14		V
Maximum output voitage	V _{O (max.2)}	$R_L \ge 2k\Omega$	±10	±13	-	V
Common-mode input voltage width	V _{CM}		±12	±14		V
Common-mode rejection ratio	CMR		70	90		dB
Supply voltage rejection ratio	SVR			30	100	μV/V
Power consumption	P _C		_		240	mW
Slew rate	SR			1.6		V/ µs
Equivalent input noise voltage	V _{ni}	$R_S=1k\Omega$, $B=10Hz$ to $30kHz$		2.5	_	μVrms
Channel separation	Sep	f=10kHz		110		dB

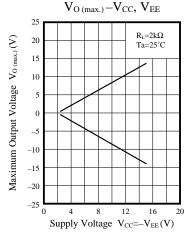
■ Characteristics Curve

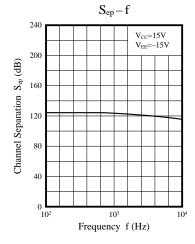


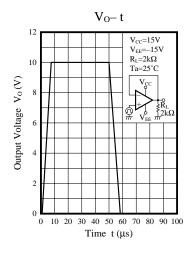


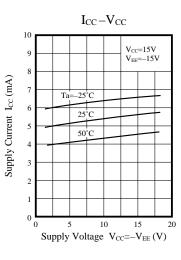












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